

DATA SHEET

NEC**MOS FIELD EFFECT TRANSISTOR****2SK4070****SWITCHING
N-CHANNEL POWER MOS FET****DESCRIPTION**

The 2SK4070 is N-channel MOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

FEATURES

- Low on-state resistance
 $R_{DS(on)} = 11 \Omega$ MAX. ($V_{GS} = 10 \text{ V}$, $I_D = 0.5 \text{ A}$)
- Low gate charge
 $Q_G = 5 \text{ nC}$ TYP. ($V_{DD} = 450 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 1.0 \text{ A}$)
- Gate voltage rating : $\pm 30 \text{ V}$
- Avalanche capability ratings

<R> ORDERING INFORMATION

| PART NUMBER | LEAD PLATING | PACKING | PACKAGE |
|-----------------------------------|---------------|------------------|-----------------------------|
| 2SK4070-S15-AY ^{Note} | Pure Sn (Tin) | Tube 70 p/tube | TO-251 (MP-3-a) typ. 0.39 g |
| 2SK4070(1)-S27-AY ^{Note} | | Tube 75 p/tube | TO-251 (MP-3-b) typ. 0.34 g |
| 2SK4070-ZK-E1-AY ^{Note} | | Tape 2500 p/reel | TO-252 (MP-3ZK) typ. 0.27 g |
| 2SK4070-ZK-E2-AY ^{Note} | | | |

Note Pb-free (This product does not contain Pb in external electrode.)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| | | | |
|-----------------------------------------------------------------------|----------------|-----------------|------------------|
| Drain to Source Voltage ($V_{GS} = 0 \text{ V}$) | V_{DSS} | 600 | V |
| Gate to Source Voltage ($V_{DS} = 0 \text{ V}$) | V_{GSS} | ± 30 | V |
| Drain Current (DC) ($T_C = 25^\circ\text{C}$) | $I_{D(DC)}$ | ± 1.0 | A |
| Drain Current (pulse) ^{Note1} | $I_{D(pulse)}$ | ± 4.0 | A |
| Total Power Dissipation ($T_C = 25^\circ\text{C}$) | P_{T1} | 22 | W |
| Total Power Dissipation ($T_A = 25^\circ\text{C}$) ^{Note2} | P_{T2} | 1.0 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -55 to $+150$ | $^\circ\text{C}$ |
| Single Avalanche Current ^{Note3} | I_{AS} | 0.8 | A |
| Single Avalanche Energy ^{Note3} | E_{AS} | 38.4 | mJ |

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

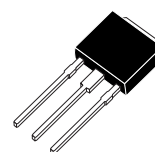
2. Mounted on glass epoxy board of $40 \text{ mm} \times 40 \text{ mm} \times 1.6 \text{ mm}$

3. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 150 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

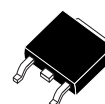
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(TO-251)



(TO-252)

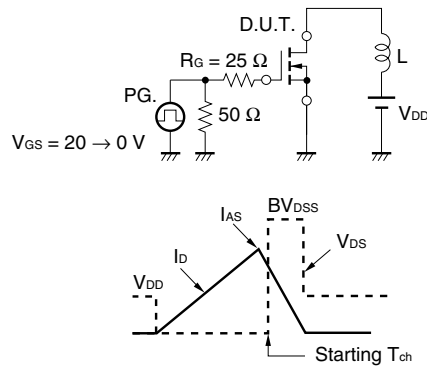


ELECTRICAL CHARACTERISTICS (T_A = 25°C)

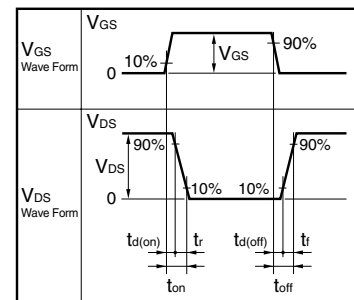
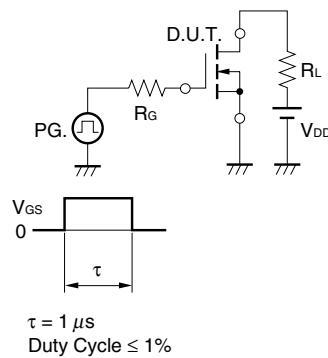
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------------------------------------|----------------------|-----------------------------------------------------------------------------|------|------|------|------|
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = 600 V, V _{GS} = 0 V | | | 100 | μA |
| Gate Leakage Current | I _{GSS} | V _{GS} = ±30 V, V _{DS} = 0 V | | | ±100 | nA |
| Gate Cut-off Voltage | V _{GS(off)} | V _{DS} = 10 V, I _D = 1 mA | 2.5 | 2.9 | 3.5 | V |
| Forward Transfer Admittance Note | y _{fs} | V _{DS} = 10 V, I _D = 0.5 A | 0.2 | 0.4 | | S |
| Drain to Source On-state Resistance Note | R _{DS(on)} | V _{GS} = 10 V, I _D = 0.5 A | | 9.2 | 11 | Ω |
| Input Capacitance | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, | | 110 | | pF |
| Output Capacitance | C _{oss} | f = 1 MHz | | 50 | | pF |
| Reverse Transfer Capacitance | C _{rss} | | | 11 | | pF |
| Turn-on Delay Time | t _{d(on)} | V _{DD} = 150 V, I _D = 0.5 A, V _{GS} = 10 V, | | 7.5 | | ns |
| Rise Time | t _r | R _G = 10 Ω | | 6 | | ns |
| Turn-off Delay Time | t _{d(off)} | | | 11 | | ns |
| Fall Time | t _f | | | 18 | | ns |
| Total Gate Charge | Q _G | V _{DD} = 450 V, V _{GS} = 10 V, | | 5 | | nC |
| Gate to Source Charge | Q _{GS} | I _D = 1.0 A | | 1 | | nC |
| Gate to Drain Charge | Q _{GD} | | | 2.8 | | nC |
| Body Diode Forward Voltage Note | V _{F(S-D)} | I _F = 1.0 A, V _{GS} = 0 V | | 0.86 | 1.5 | V |
| Reverse Recovery Time | t _{rr} | I _F = 1.0 A, V _{GS} = 0 V, | | 135 | | ns |
| Reverse Recovery Charge | Q _{rr} | di/dt = 100 A/μs | | 285 | | nC |

Note Pulsed

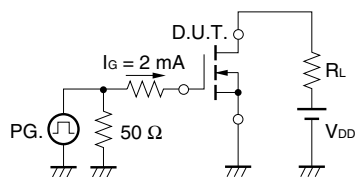
TEST CIRCUIT 1 AVALANCHE CAPABILITY



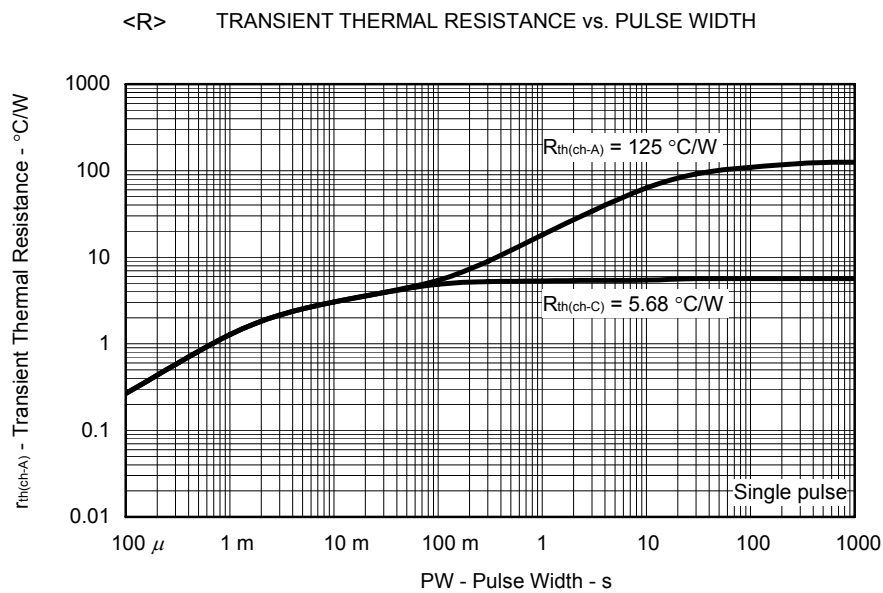
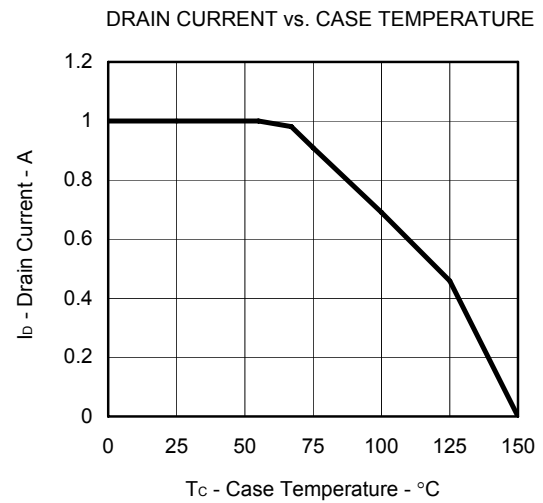
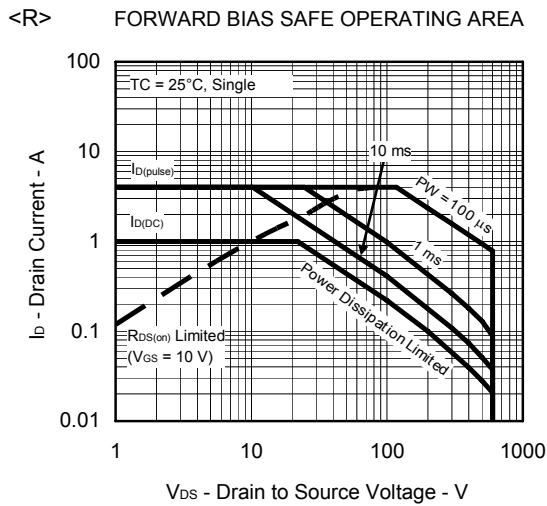
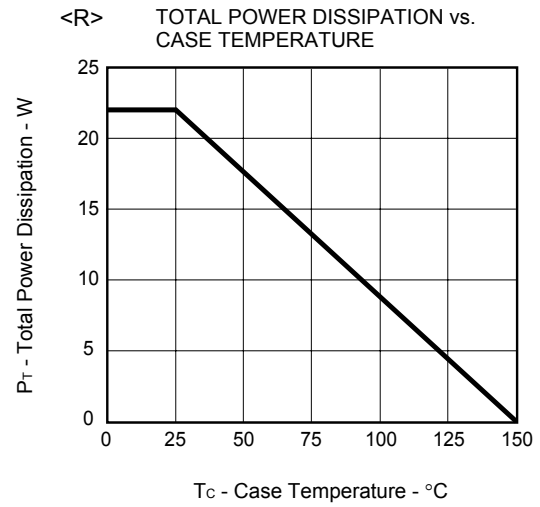
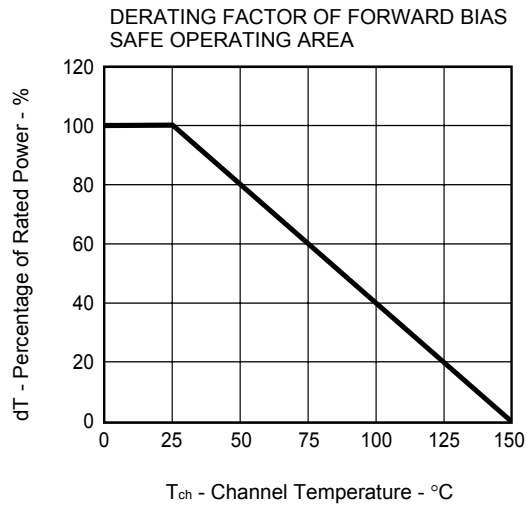
TEST CIRCUIT 2 SWITCHING TIME



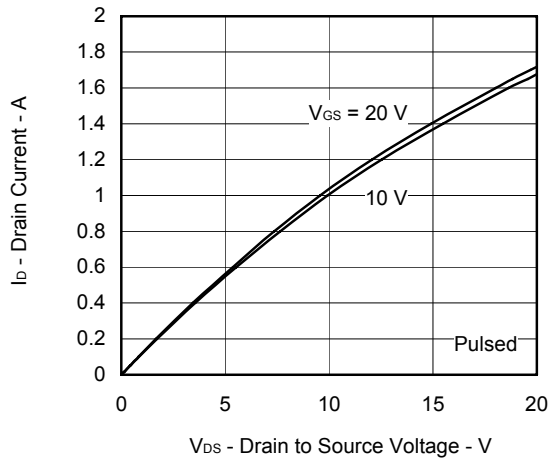
TEST CIRCUIT 3 GATE CHARGE



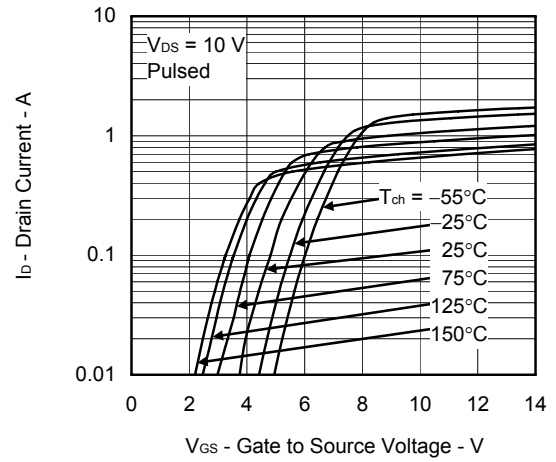
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



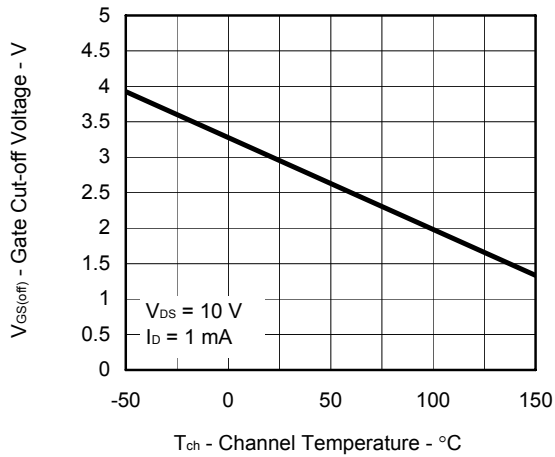
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



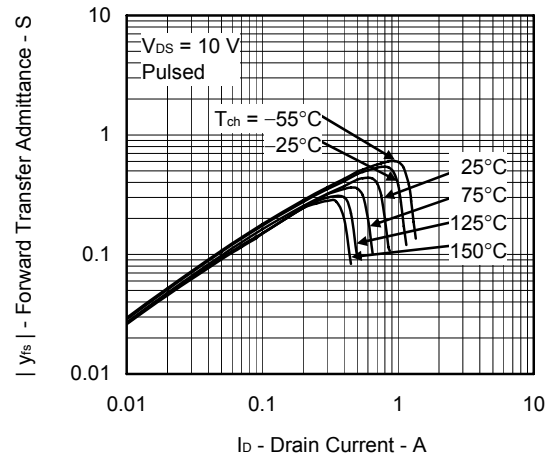
FORWARD TRANSFER CHARACTERISTICS



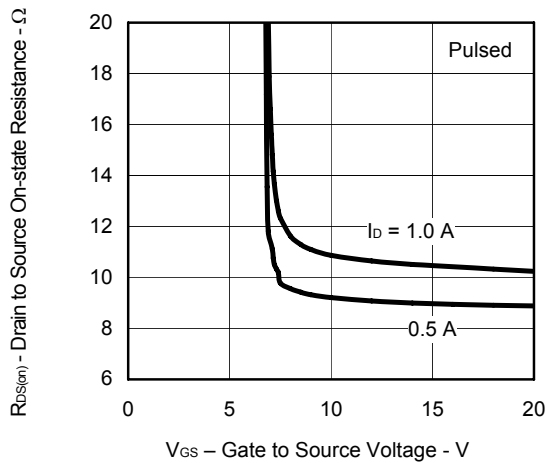
GATE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



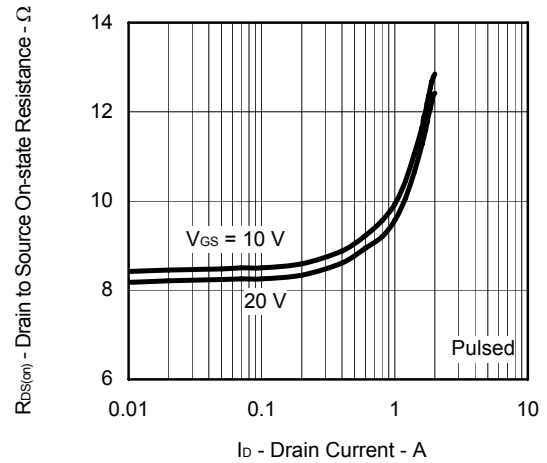
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT

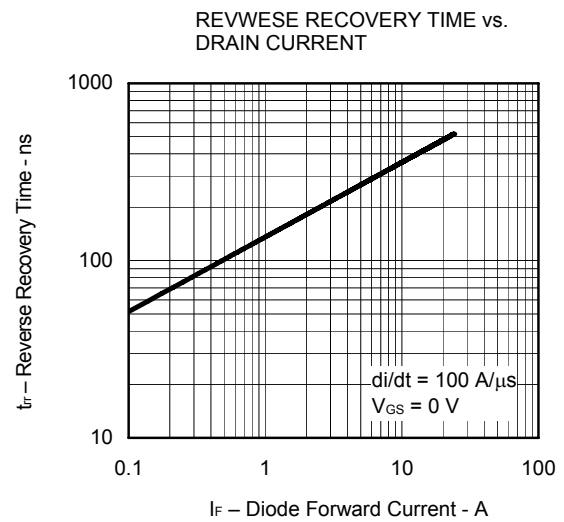
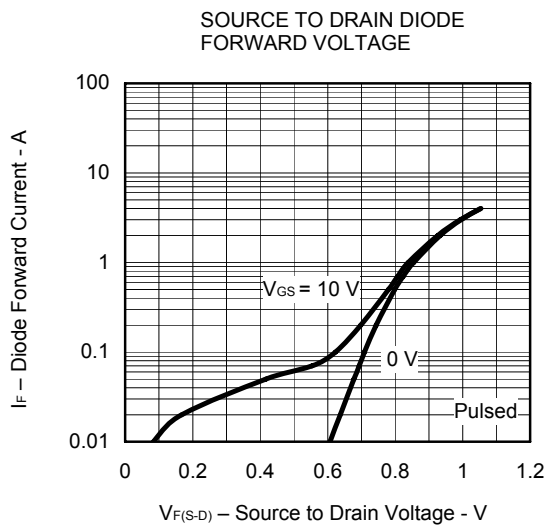
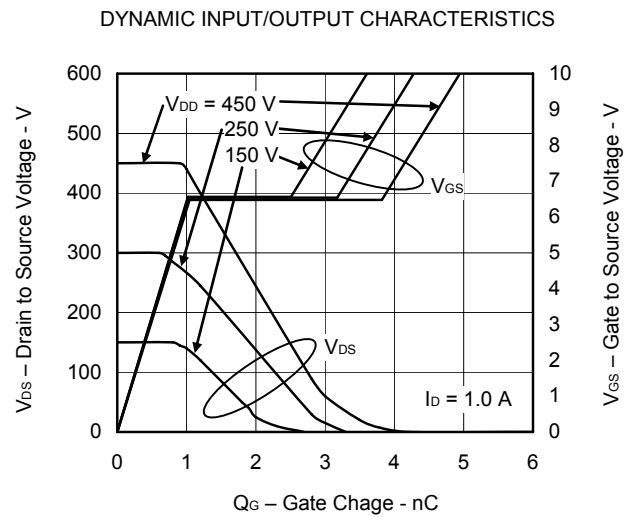
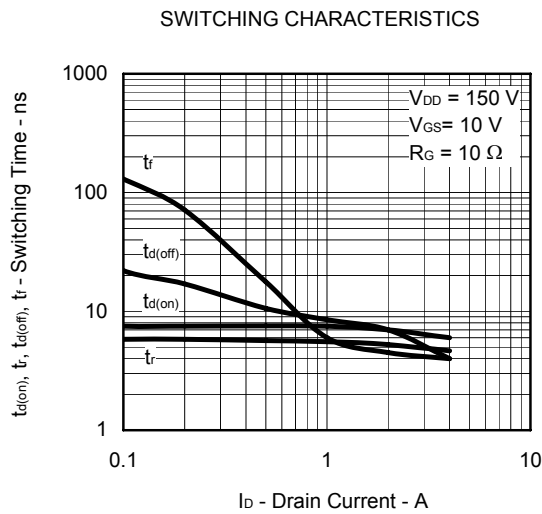
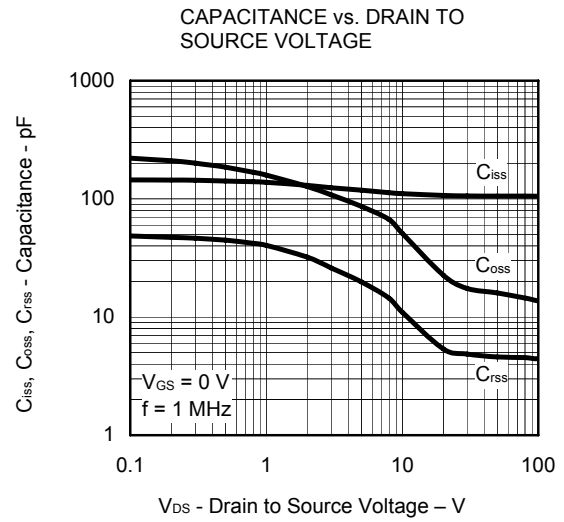
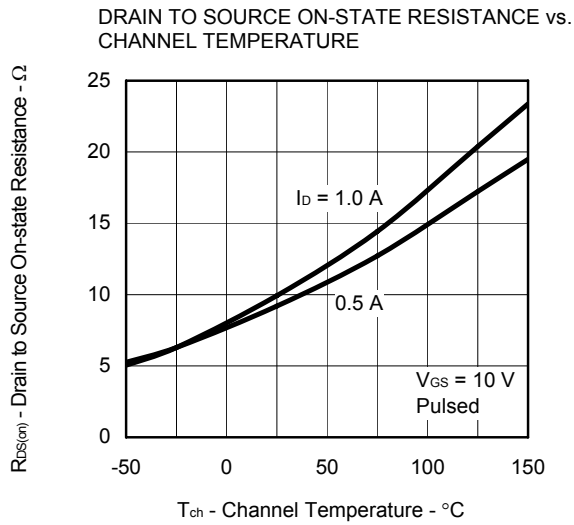


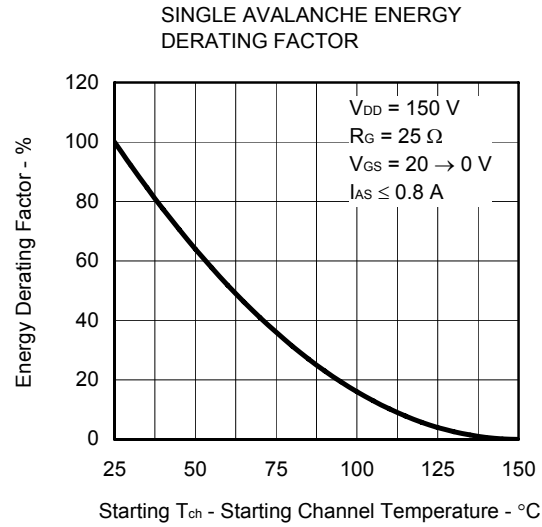
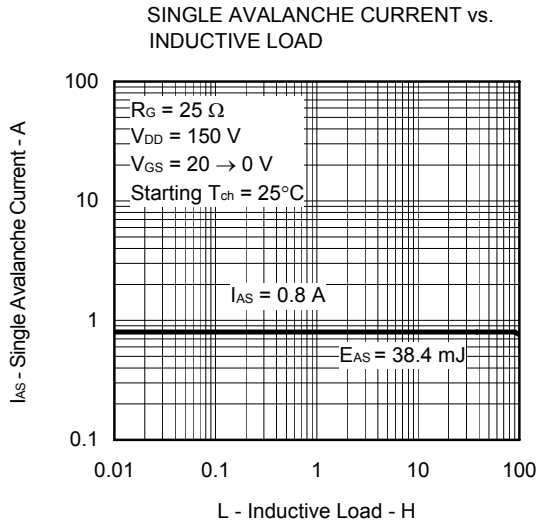
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE
RESISTANCE vs. DRAIN CURRENT

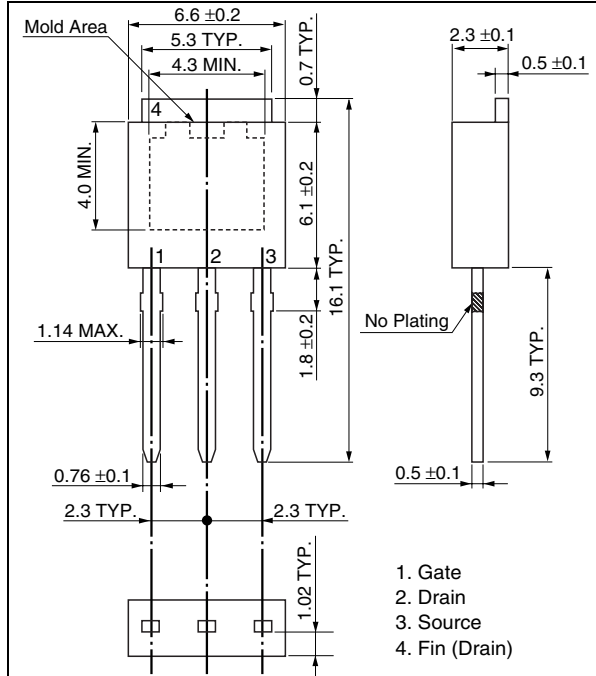




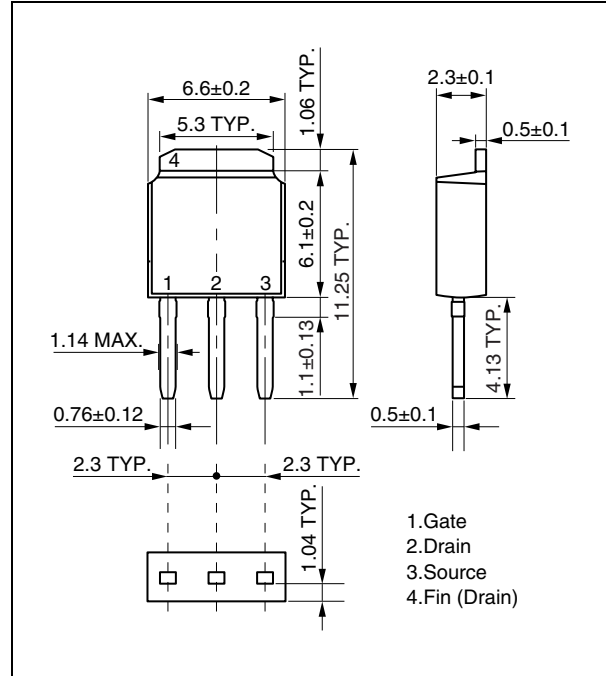


<R> PACKAGE DRAWINGS (Unit: mm)

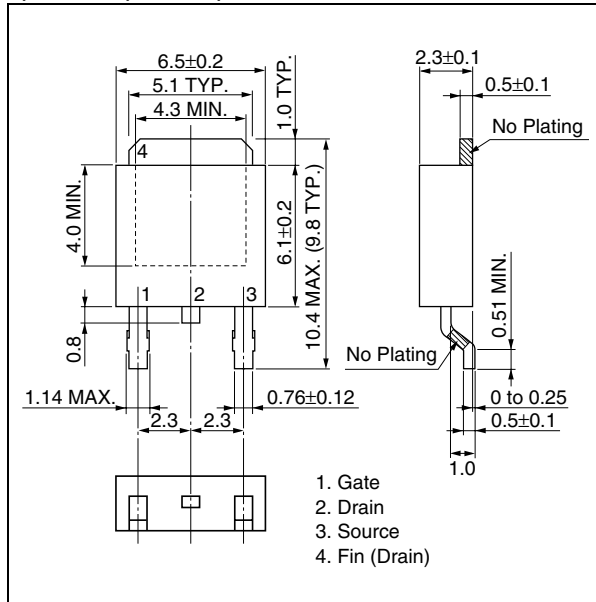
1) TO-251 (MP-3-a)



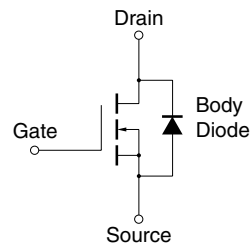
2) TO-251 (MP-3-b)



3) TO-252 (MP-3ZK)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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